

## Properties of MnO doped graphene synthesized by co-precipitation method

*M. Ilman Nur Sasongko<sup>3</sup>, Poppy Puspitasari<sup>1,2</sup>,  
Sukarni<sup>1</sup>, Cipi Yazirin<sup>3</sup>*

<sup>1</sup>Mechanical Engineering Department, Engineering Faculty, Universitas Negeri Malang, Semarang Street No. 5, Malang, East Java, Indonesia

<sup>2</sup>Center of Advanced Materials, Universitas Negeri Malang, Semarang Street No. 5, Malang, East Java, Indonesia, 65140

<sup>3</sup>Master Student, Postgraduate Program, Universitas Negeri Malang, Semarang Street No. 5, Malang, East Java, Indonesia

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MnO doped graphene specimens were synthesized using a simple and cost-effective method, i.e. co-precipitation. The characterization of specimens was done through various techniques, such as X-ray Diffraction (XRD), Scanning Electron Microscopy (SEM), and Fourier Transform Infrared (FTIR). Single phase pattern on [222], crystallite size, and *d*-spacing were confirmed by XRD results. The nanostructure morphology was observed using SEM. FTIR showed the shifted peaks and changes in the intensity of molecular bonds of the material. The specimens were sintered for 1 h at various temperatures of 500 °C, 600 °C, and 700 °C. The XRD characterization showed that sintering at 700 °C resulted in MnO and GO peaks with the highest intensity, but the specimen sintered at 600 °C had the best grain size of 70.39 nm. The morphology characterization by SEM showed a change of shape from triangle to nanosphere with agglomeration. The results of FTIR showed that the shifts in C-O and Mn-O groups were followed by an increase in N-H, C-H, C=O, C-O, and Mn-O. The results of this study suggest that single-phase MnO doped graphene was successfully synthesized using the co-precipitation method.

**Keywords:** characterization, co-precipitation, graphene, MnO, synthesis.

Образцы графена с примесью MnO синтезированы с использованием простого и экономически эффективного метода совместного осаждения. Характеристика образцов проводилась с помощью различных методов, таких как рентгеновская дифракция (XRD), сканирующая электронная микроскопия (SEM) и инфракрасное преобразование Фурье (FTIR). Однофазный состав в направлении [222], размер кристаллитов и *d*-интервал подтверждены результатами XRD. Морфологию наноструктур наблюдали с использованием SEM, FTIR показал сдвинутые пики и изменения интенсивности молекулярных связей материала. Образцы спекали в течение 1 часа при различных температурах 500 °C, 600 °C и 700 °C. Характеристика XRD показала, что спекание при 700 °C приводило к максимальным пикам MnO и GO, но образец, спеченный при 600 °C, имел лучший размер зерна 70,39 нм. Характеристика морфологии SEM показала изменение формы от треугольника до наносферы с агломерацией. Результаты FTIR свидетельствуют, что сдвиги в группах C-O и Mn-O сопровождалось увеличением N-H, C-H, C = O, C-O и Mn-O. Результаты этого исследования доказывают, что однофазный легированный MnO графен был успешно синтезирован с использованием метода совместного осаждения.

**Властивості графена з домішкою MnO, синтезованого методом співосадження.**  
*M. Ilman Nur Sasongko, Poppy Puspitasari, Sukarni, Cepi Yazirin*

Зразки графена з домішкою MnO синтезовано з використанням простого і економічно ефективного методу спільного осадження. Характеристика зразків проводилася за допомогою різних методів, таких як рентгенівська дифракція (XRD), скануюча електронна мікроскопія (SEM) і інфрачервоне перетворення Фур'є (FTIR). Однофазний склад у напрямку [222], розмір кристалітів і *d*-інтервал підтверджено результатами XRD. Морфологію наноструктур спостерігали з використанням SEM. FTIR показав зсунуті піки і зміни інтенсивності молекулярних зв'язків матеріалу. Зразки спікаються протягом 1 години при різних температурах 500 °C, 600 °C і 700 °C. Характеристика XRD показала, що спікання при 700 °C призводило до максимальних піків MnO і GO, але зразок, спечений при 600 °C, мав кращий розмір зерна 70,39 нм. Характеристика морфології SEM показала зміну форми від трикутника до наносфери з агломерацією. Результати FTIR свідчать, що зсуви у групах C-O і Mn-O супроводжувалися збільшенням N-H, C-H, C = O, C-O і Mn-O. Результати цього дослідження показують, що однофазний легований MnO графен успішно синтезовано з використанням методу спільного осадження.

## 1. Introduction

Over the past few years, the development of alternative materials for high-capacity and eco-friendly energy storage applications has been widely studied. Given the ever-increasing use of fossil fuels, many studies have been conducted to develop energy storage materials for replacing fossil fuels. The use of manganese oxide by far has been broadening as the key ingredient in producing energy storage system due to its good magnetic properties.

Manganese oxide is a manganese mineral that can be found in nature and has naturally formed oxides. Manganese oxide has its uniqueness, such as a very high magnetic moment of 0.326 emu/g and a grain size of 7.7 nm [1]. The smaller the grain size, the higher the magnetic properties, meaning that it is suitable for core-shell lithium-ion battery [1]. As described by [2], manganese oxide also has a high purity level, which can be used as an adsorbent for the removal of dyes from textile waste by adsorbing molecules and as a very good cation, i.e. 0.49 a.u. In line with [1], [3] proved that manganese oxide has excellent electrochemical properties (61.43 F.g<sup>-1</sup>) and potential use in batteries.

Another material that has been extensively studied for the development of energy storage materials is graphene. Graphene has attracted interest from many researchers due to its unique and remarkable properties and great potential applications in many fields, one of which for alternative energy storage. According to [4,5], graphene oxide is a single graphite oxide sheet with oxygen-containing functionalities bearing on the basal planes and edges. Graphene

oxide is obtained by peeling off the graphite oxide. The oxygen functional group can facilitate the modification of the surface of graphene oxide and make it a promising material for composites [6].

In [4] conducted a study on MnO doped graphene, in which graphene was protected by manganese oxide with a very high magnetization of 1.0-10<sup>3</sup> emu/m<sup>3</sup> due to the exchange interactions between impurity ions mediated by Mn. In the study, MnO<sup>4-</sup> ions in the KMnO<sub>4</sub> electrolyte with three electrons and protons turned into MnO. In [5] conducted a study on the calcination of MnO<sub>2</sub> composites and graphene reduction at 500 °C. The research was successful, resulting in a material with a reversible capacity of 900 and 750 mAh that worked well as an active ingredient for lithium-ion batteries. In addition to the two methods, others can be used such as modified Hummers method [6-9], novel and facile method [10, 11], co-precipitation methods [12] and so forth.

The co-precipitation method is a very easy method of synthesizing oxide nanoparticles [12]. Moreover, it can result in narrow particle size distributions (Cao, 2004). This method can also improve the crystal structure and properties of the material. The improvement of structure and properties can occur optimally if the synthesis parameters are controlled, such as precursors, material preparation, pH, temperature, stirring speed and time, and surfactant concentration [13].

Sintering is the process of drying and shrinking to obtain a wider surface area and increase the purity of nanomaterials [14-19]. Material that has been synthesized is then characterized to identify changes in properties and purity. Characterization is divided

into several types, namely X-Ray Diffraction (XRD), Scanning Electron Microscopy (SEM), and Fourier Transform Infrared (FTIR). XRD result confirms single phase pattern, crystallite size, and d-spacing. SEM aims to observe the morphology of nanostructure. FTIR shows the shifted peak and intensity of the molecular bond of the material.

## 2. Experimental

The synthesis was conducted using co-precipitation method. First, 2.9990 gram MnO powder and 0.0010 gram GO were prepared; an analytical balance manufactured by Optima Scale was used for the weighing. The next step was mixing the MnO powder with 30 ml ethylene glycol using a Cimarec II Thermo magnetic stirrer for 1 h. The GO was then added to the mixture while the magnetic stirrer was still spinning, and left stirring for 3 h. The stirring process aimed to mix MnO and GO thoroughly. In addition to mixing, stirring also dissolved the MnO and GO so that GO could enter the molecule structure of MnO. After that, the mixture was heated using the magnetic stirrer at 70-80 °C for 2 h until it turned into sol. It was washed 4 times with 750 ml distilled water to neutralize the moisture content, monitored using a pH meter until pH 11 was achieved, and filtered using filter paper. The washing process with distilled water aimed at neutralizing the acid solution. Washing with NaOH was also done for 3 times. The filter paper used to filter MnO doped GO was dried in the oven at 120 °C for 3 hours, aiming to produce a dry powder. The next stage was scraping the residue off the dried filter paper and crushed it for 1 h to break up the MnO doped GO powder into smaller particles. After crushing, sintering was performed at various temperatures (500 °C, 600 °C, and 700 °C) for 1 h in a tube furnace (MTI corporation). The sintering result was then crushed for 1 h. Scanning electron microscopy (FEI Inspect-S50) was used for morphological characterization, x-ray diffraction (PANalytical) for phase characterization, and Fourier transform infrared (IR Prestige 21, Shimadzu) for oxide group characterization.

## 3. Results and Discussion

### Phase Characterization

The X-ray diffraction analysis aimed to compare the crystalline phases in the material powder and analyze the properties of the structure, including crystallite size, phase composition, crystal orientation, and

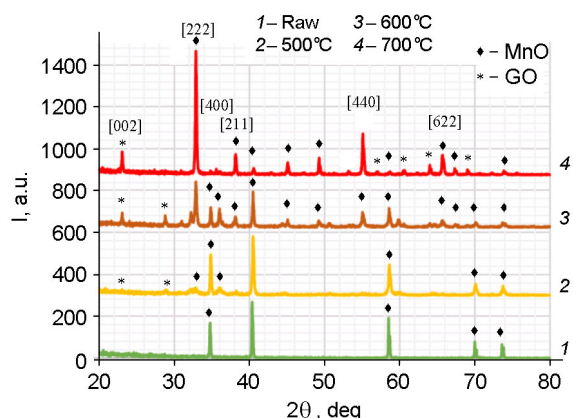


Fig 1. Phase identification of raw MnO and MnO doped graphene with different sintering temperatures.

crystal defects in each identification phase. The following is the XRD results of MnO doped graphene with different sintering temperatures presented in a phase diagram.

Fig 1. shows the structural phase transitions of the four MnO doped graphene specimens sintered at different temperatures. The green(1) graph shows the specimen not subjected to any treatment (raw material), the result of which formed the basis for observing the initial phase changes of those synthesized and sintered at different temperatures. Phase changes occurred after synthesis under sintering temperature variations (500 °C, 600 °C, and 700 °C). The different shift of crystalline intensities (as shown in Fig. 1) shows the development of nanoparticles in MnO doped graphene. The development of these nanoparticles indicates an increase in the purity level of MnO doped graphene nanoparticles.

Each phase was characterized by its peaks. Peak [111], [200], [220], [311] and [222] represented the peaks of MnO [2], [20] and [21], while peak [002] represented graphene [6], [22]. The peak that underwent a shift was peak [222]. This could happen because the sintering process was done. The phase growth was caused by the molecular development of MnO-GO during sintering at various temperatures of 500 °C, 600 °C, and 700 °C. Peak growth indicates a rapid increase in the purity level of MnO-GO powder. The purity during the sintering process started to increase when the sintering temperature was 500 °C (as shown in the yellow graph at 40°). The increase was shown by index [211], but the increase of GO peaks was not apparent, meaning that the growth of GO was not found in the development of

Table. Intensity, FWHM, *d*-spacing and Crystallite Size of MnO Doped Graphene Oxide

Sample Material	X-Ray Diffraction (correspond to [222] peak)			
	Intensity (counts)	FWHM (degree)	<i>d</i> -spacing (Å)	Crystalline size (nm)
Raw Manganese Oxide (MnO)	264.33	1.03	2.23	143.44
Manganese Oxide Doped Graphene Oxide (MnO-GO) 500 °C	277.69	2.7	2.23	54.75
Manganese Oxide Doped Graphene Oxide (MnO-GO) 600 °C	210.64	2.1	2.72	70.39
Manganese Oxide Doped Graphene Oxide (MnO-GO) 700 °C	584.58	1.7	2.72	85.05

MnO-GO nanopowder sintered for 1 hour at 500 °C. A very noticeable difference existed in MnO-GO nanopowder sintered at 600 °C and 700 °C. Under these sintering temperatures, MnO-GO nanopowder gradually showed an increase at 23° 2 Th and 33° 2 Th. At 600 °C, the peak intensity of MnO and GO powder increased. As shown by the position of 23° 2Th, the specimen sintered at 600 °C experienced an increase in GO intensity with index [002], i.e. 43.80 cts. The MnO peak at 33° 2 Th and index [222] had an intensity of 210.64 cts. The MnO-GO specimen sintered at a 700 °C also experienced a similar condition where the intensity of GO reached 85.90 cts at 23° 2Th and index [002], and that of MnO reached 584.58 cts at 33° 2 Th and index [222]. Peak growth occurred because the atoms present in MnO-GO nanopowder that contain electrons reacted and spread very rapidly. As shown in the graph, the peaks of specimens sintered at 600 °C and 700 °C shifted, indicating an increase in the MnO-GO powder successively (Muhammad Ilman Nur Sasongko). The phenomenon showed that a single phase occurred at a 700 °C and index [222]. Single phase is a straight line pulled above some peak intensities of crystallinity resulted from some variations in the treatment given and showed that the cubic structure centered in the MnO nanopowders contained electrons in each atom and also a large number in the lattice.

The results of XRD characterization can also determine the crystallite size of MnO-GO material using the following Scherer Equation [23, 24]

$$d = \frac{K \cdot \lambda}{\beta \cos \theta}$$

where:

*d*, crystallite diameter; *K*, constant = 0.89-0.9;  $\lambda$ , wavelength = 1.5406 Å;  $\beta$ , full-width half maximum (FWHM)

The results of calculation using the above formula are presented in Table.

Table shows that the crystallite size of specimens sintered at different temperatures. Size variations were affected by the duration of the crushing process, whereas the difference in crystalline purity or intensity was influenced by the variations in sintering time. The size variation was evident in MnO-GO sintered at 700 °C for 1 h with the highest purity level of 584.58 and the largest crystal size of 85.05 nm among the other synthesized specimens. The MnO-GO specimen sintered at 500 °C had the smallest crystal size of 54.75, and its purity did not increase significantly. The purity level of raw MnO was 1.33% higher than MnO-GO at index [211]. The level of purity only increased in MnO, whereas the development of atoms in GO was not visible. The MnO-GO specimens sintered at 600 °C and 700 °C experienced different conditions. GO atoms increased significantly at index [002], and the development of MnO atoms occurred at index [222]; the longer the sintering time and the higher the temperature (according to the atomic development limit of MnO), the higher the purity level (Muhammad Ilman Nur Sasongko). Among the three sintering temperatures, the temperature of 700 °C generated a specimen with the best purity and size, i.e. a purity level of 584.58 cts and 85.05 nm in size. It can be concluded that the use of co-precipitation method can produce MnO-GO nanopowder with great purity level and small crystallite size compared to the raw MnO powder of micron size. XRD test results.

#### Morphological Characterization

The SEM was used to analyze and compare the morphology of MnO materials, before and after synthesis [25, 26]. The analysis aimed to examine whether there was any change in the morphology of MnO-GO after undergoing synthesis with different sinter-

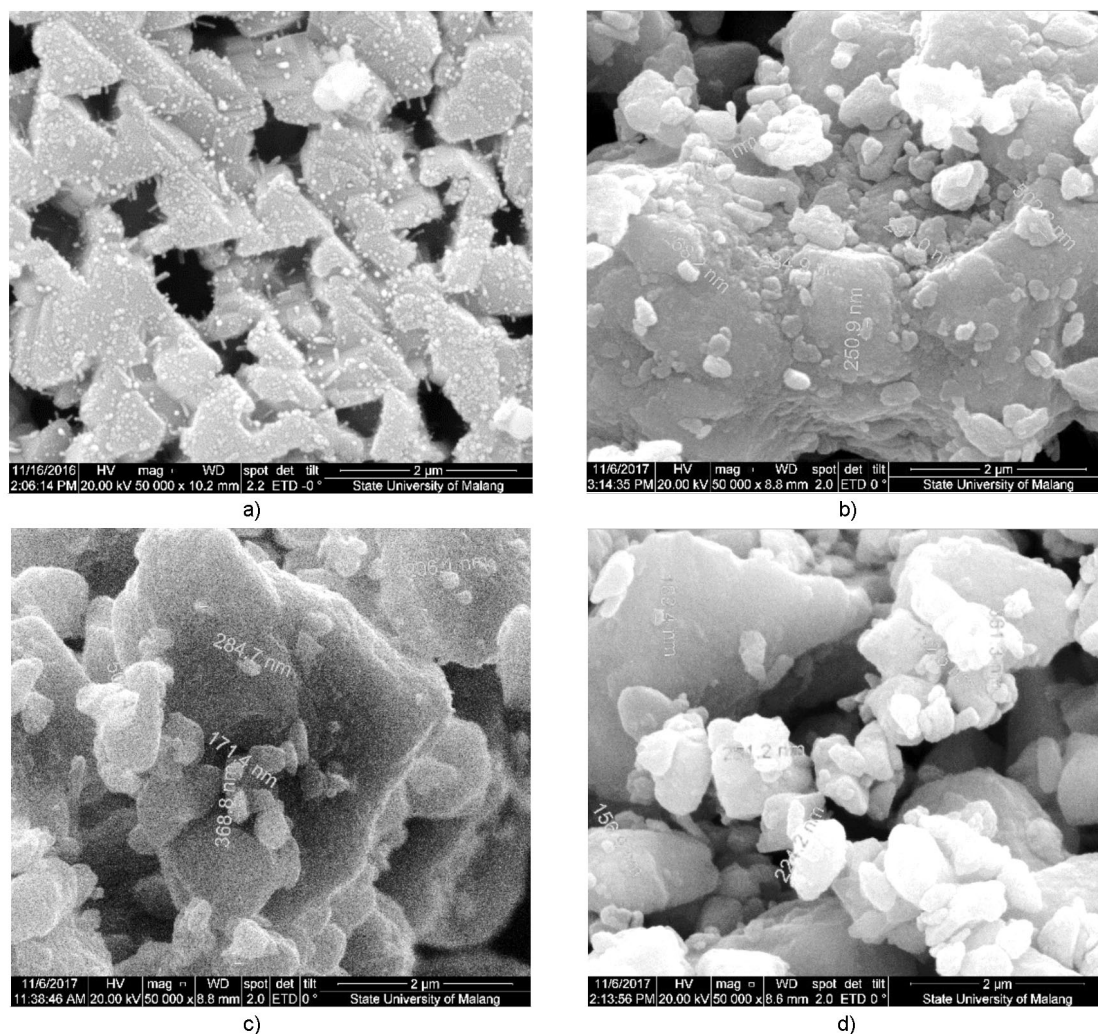


Fig 2. Morphology of manganese oxide (MnO) at 50K magnification: (a) without graphene, (b) MnO doped graphene with sintering at 500 °C, (c) MnO doped graphene with sintering at 600 °C, and (d) MnO doped graphene with sintering at 700 °C.

ing temperatures. Morphological changes that occurred in the synthesized MnO-GO with variations in sintering temperature as the results of SEM are shown in Fig. 2.

The different morphologies of MnO-GO can be seen from the results of SEM at a magnification of 50K. The results showed morphological changes in MnO due to variations in sintering temperature. The changes were caused by the use of various sintering temperatures, as stated by [14] that molecular change occurs due to sintering. During sintering, drying and shrinkage are formed due to molecular reactions occurring at room temperature. Under these conditions the mixed materials have many characteristics and MnO-GO which corresponds to the sintering temperature range, starting from 600 °C to 1000 °C.

Fig. 2a shows the morphology of raw MnO the one that was not synthesized and sintered. The SEM results were obtained by examining the morphology of the raw MnO at 50K magnification. The results showed that the raw MnO was triangular with some parts resembling a trapezium with the smallest size of 65.39 µm and the largest size of 91.23 µm. The difference in the grain size and shape on the surface indicates that agglomeration occurred as particles deposited in the membrane of the MnO grains. The MnO specimens were tested using SEM to determine the initial size of MnO powder prior to synthesis.

As shown in Fig. 2b, the morphological changes in MnO-GO after being sintered at 500 °C could be analyzed from the results of SEM at a magnification of 50K. After the synthesis process, the initial shape of raw

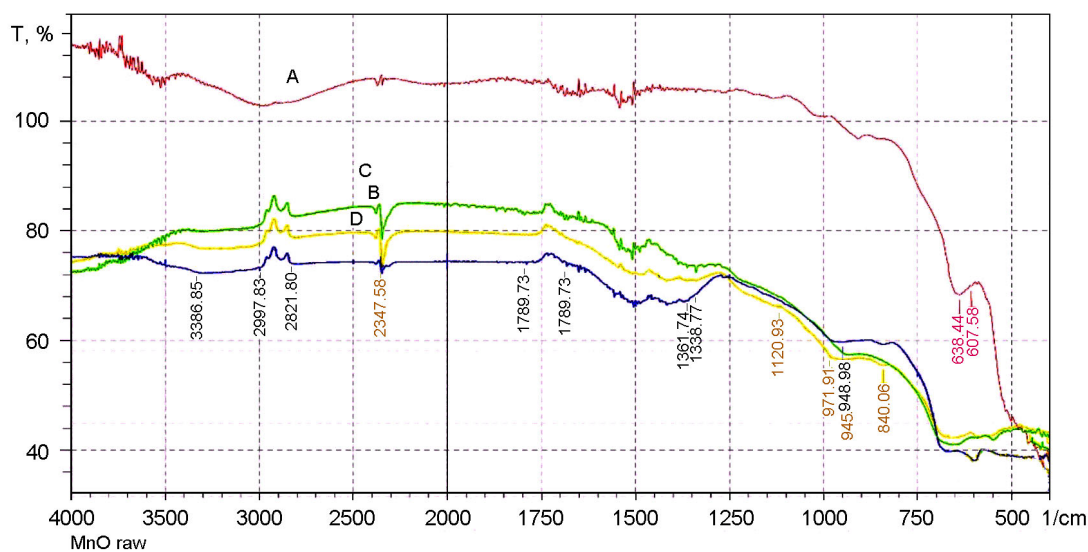


Fig. 3. Difference in oxide groups of manganese oxide (MnO) doped graphene powder (a) without graphene, (b) MnO doped graphene with sintering at 500 °C, (c) MnO doped graphene with sintering at 600 °C, and (d) MnO doped graphene sintering at 700 °C.

MnO (triangular with little dots) turned into spheres with uneven agglomeration. The sphere size was not uniform at some parts of the surface of MnO-GO specimen sintered at 500 °C; the largest one was 234.9 nm, while the smallest was 502.8 nm. The changes were influenced by the sintering temperature (500 °C) and the duration of the crushing process. The morphological changes shown in Fig. 2a and 2b indicate that the synthesis had been successfully done.

The results of SEM at 50K magnification (as shown in Fig. 2c) showed an insignificant change in the MnO-GO morphology as a result of sintering at 600 °C, if compared to the one sintered at 500 °C. However, larger agglomeration occurred in MnO-GO sintered at 600 °C. The uniformity of the grain size was not that different from the MnO-GO sintered at 500 °C. The smallest size was 171.4 nm, and the largest one was 501.4 nm. The changes were affected by the sintering temperature of 600 °C and the duration of the crushing process. The results indicate that the process of transforming MnO from micron to nano has been successfully performed.

Fig. 2d shows that a more considerable difference in agglomeration existed in MnO sintered at 700 °C than those sintered at 500 °C and 600 °C. The agglomeration occurred formed small groups with differences in shape and size. The specimen sintered at 700 °C had the smallest grain of 152.5 nm and the largest one of 152.5 nm. The morphological changes were influenced

by the sintering temperature (700 °C) and the duration of the crushing process. It can be concluded that the transition of MnO from micro to nano was successful. Great differences in the size and shape of the grains on the coated surfaces showed that large agglomeration occurred after having been synthesized by sintering at 700 °C. This could occur due to the synthesis method, sintering temperature, uneven crushing, and crushing duration.

#### Characterization of Oxide Groups

The FTIR analysis was conducted to analyze the oxide clusters in MnO, before and after the synthesis with variations in sintering temperature (500 °C, 600 °C, and 700 °C).

Fig. 3 shows the FTIR spectrum of the MnO specimens; the line 3a represents the raw MnO-GO, and the lines 3b, 3c, and 3d represent the MnO-GO sintered at 500 °C, 600 °C, and 700 °C, respectively. As shown in Fig. 3, one peak shifted and decreased. N-H group occurred at 3500-3400  $\text{cm}^{-1}$  [27], while an increase in -OH occurred at 3386.85  $\text{cm}^{-1}$  [27]. At 2821.80  $\text{cm}^{-1}$ , the -CH group was stable. An increase in GO due to manganese oxide resulted in an increase in hydroxyl and carbonyl/carboxyl groups. The sintering temperature caused a decrease in N-H group and an increase in -OH and -CH groups, as shown by the green line [28, 29].

At 1732  $\text{cm}^{-1}$ , C=O group decreased consecutively [29]. A decrease occurred in C=C group at 1633  $\text{cm}^{-1}$ , C-O group at 1361.74  $\text{cm}^{-1}$ , C=O epoxide group at 1000  $\text{cm}^{-1}$ ,

and CO group at 940-948.89  $\text{cm}^{-1}$  [27,30]. The presence of mostly C-O and C-C groups indicates that graphene oxide began to enter into the lattice of MnO as shown in 3b-3d at 1732  $\text{cm}^{-1}$  to 940  $\text{cm}^{-1}$  [27,29]. It was influenced by the mixing of MnO and GO powder and various sintering temperatures (500 °C, 600 °C, and 700 °C).

As represented by 3a-3d, C-H group at 665.44-651.94  $\text{cm}^{-1}$  was deformed due to sintering and ethylene glycol as a binder [27]. At 638.44-607.58  $\text{cm}^{-1}$ , the specific vibrations of Mn-O bonds could be superposed [30, 31]. The positions of 472.56  $\text{cm}^{-1}$  to 418.55  $\text{cm}^{-1}$  included at ~500, where its intensity decreased with the increase of MnO content [30-32]. [31] also explained that high MnO content existed at 418.55  $\text{cm}^{-1}$  to 638.44  $\text{cm}^{-1}$ .

#### 4. Conclusions

The results of phase characterization obtained from XRD have led us to conclude that the sintering process at 700°C for 1 h. produced the best MnO-GO among other treatments, i.e. sintering 500°C and 600°C. The XRD analysis showed that the MnO-GO sintered at 700°C was a single phase with the highest intensity of 584.58 counts in MnO and 85.90 counts in GO. The crystallite size was 85.05 nm, but still a nanometer-scale particle.

The morphology of raw MnO was triangular, and MnO-GO was in the form of nanospheres. The morphological difference showed a change from micro to nano at 50K magnification. The MnO-GO sintered at 700°C had the smallest crystallite size of 152.5 nm and the largest crystallite size of 361.3 nm. The MnO-GO sintered at 500°C had the smallest crystallite size of 234.9 nm and the biggest crystallite size of 502.3 nm. The MnO-GO sintered at 600°C had the smallest crystallite size of 171.4 nm and the largest crystallite size of 501.4 nm.

The results of the FTIR analysis on the oxide groups of the synthesized MnO-GO sintered for various sintering temperatures showed that the shift in C-O and Mn-O was due to the temperature variations, followed by an increase at 3386.85  $\text{cm}^{-1}$ , 2821.80  $\text{cm}^{-1}$ , 940-1732  $\text{cm}^{-1}$ , and 418.55  $\text{cm}^{-1}$  to 638.44  $\text{cm}^{-1}$ , i.e. -OH, C-H, C=O, C-O, and Mn-O. In fact, a difference in temperature was the contributing factor to the characterization of oxide groups; the more varied the temperatures, the more visible the shift and the increase in oxide groups.

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